

ZXCT1030 High-side current monitor with comparator

Description

The ZXCT1030 is a high side current sense monitor containing an internal reference and comparator with a non-latching output. Using this device eliminates the need to disrupt the ground plane when sensing a load current.

Features

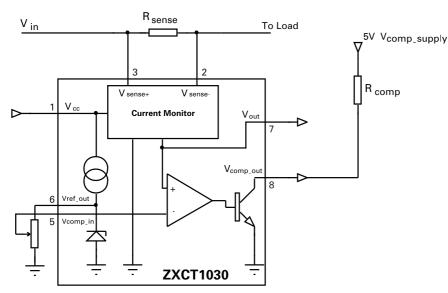
- Low cost, accurate high-side current sensing
- Output voltage scaling
- Up to 18V output
- 2.2V 20V supply range
- Voltage reference on chip
- Comparator on chip
- SO8 package

Typical application circuit

The wide input voltage range of 20V down to as low as 2.2V make it suitable for a range of applications. Dynamics and supply current are optimized for the processing of fast pulses, associated with switch mode applications.

Applications

- Battery chargers
- Electronic fuse
- DC motor control
- Over current monitor
- Power management
- Inrush current limiting



Ordering information

Device	Status	Package	Device marking	Reel size (inches)	Tape width (mm)	Quantity per reel
ZXCT1030X8TA	Last time buy	MSOP8	ZXCT1030	7	12	1000
ZXCT1030N8TA	Active	SO8	ZXCT1030	7	12	500

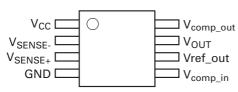
Absolute maximum ratings

Voltage on any pin	-0.6V and V _{CC} +0.6V
Operating temperature	-40 to 85°C
Storage temperature	-55 to 125°C
Package power dissipation	(T _{amb} = 25°C)
MSOP8	500mW

Recommended operating conditions

Parameter	Min.	Max.	Unit
V _{CC}	2.2	20	V
V _{SENSE+}	2.2	V _{CC}	V
V _{SENSE} ^(a)	10	500	mV
V _{OUT}	0	V _{SENSE} -1V	V
V _{comp-in}	0.005	10	V
T _{amb}	-40	85	°C

Pin-out connections



Pin name	Function			
V _{CC}	Supply voltage			
V _{SENSE-}	Negative sense input			
V _{SENSE+}	Positive sense input			
GND	Ground			
V _{comp_in}	Comparator input, usually a ratio of the reference or other control signal			
Vref_out	Reference output			
V _{OUT}	Current monitor output voltage			
V _{comp_out}	Open collector comparator output			

Symbol	Parameter	Conditions		Limits		Unit
			Min.	Тур.	Max.	
V _{CC}	V _{CC} range		2.2		20	V
V _{SENSE+}	Sense+ range		2.2		V _{CC}	
V _{OUT}	Output voltage	V _{SENSE} = 0V	0	2	10	mV
		V _{SENSE} = 10mV	88	100	112	mV
		V _{SENSE} = 30mV	284	300	316	mV
		V _{SENSE} = 50mV	480	500	520	mV
		V _{SENSE} = 100mV	970	1000	1030	mV
		V _{SENSE} = 500mV	4500	5000	5500	mV
R _{OUT}	Output resistance	$V_{SENSE} = 15V, V_{OUT} = 1V$	1.2	1.5	1.8	kΩ
V _{OUT}	V _{OUT}			30		ppm/°C
т _с	temperature coefficient					
I _{CC}	Supply current	V _{SENSE-} = 15V	170	270	350	μA
I _{SENSE+}	V _{SENSE+} input current		25	48	90	μA
I _{SENSE-}	V _{SENSE-} input current	V _{SENSE-} = 14.9V	25	70	220	nA
V _{CM(min)} ^(b)	Minimum active common	V _{CC} =15V	2.8			V
olin(iniii)	mode voltage	$V_{comp_supply} = 5V$				
		$V_{comp_{in}} = V_{REF}$				
		V _{SENSE} = 10mV				
A _{CC}	Accuracy	V _{SENSE} =100mV	-3		3	%
Gain	V _{OUT} /V _{SENSE}	V _{SENSE} = 100mV	9.7	10.0	10.3	
BW	Bandwidth	V _{SENSE} =10mVp-p		3		MHz
		V _{SENSE} = 100mVp-p		6		MHz
Comparat	or			1	1	
V _{comp_in}	Input voltage		0.005		10	V
V _H	Hysteresis			15		mV
I _B	Input bias		5	80	150	nA
T _D	Propagation delay			100		ns
V _{OL}	Output voltage low		30	150	200	mV
V _{OH}	Output voltage high				V _{comp_}	V
					supply	
I _{OL}	Output sink current	V _{OL} = 0.4V	2			mA
I _{ОН}	Output high leakage				1.0	μA
V - 14 -	current					
Voltage re	terence		4 000	1.0.10	1.000	
V _{ref}		Reference current =	1.200	1.240	1.280	V
delta V _{ref}	Change in V _{ref}	+300μA to -5μA Isource 5μA to		10		mV
acita vref	Change in Vret	Isink 300µA				
Т _С				30		ppm/°C
PSR	Supply rejection			0.01		%/V

Electrical characteristics (ZXCT1030X8) - Test conditions $T_{amb} = 25^{\circ}C$, $V_{IN} = V_{CC} = 15V$, $R_{comp} = 10kV$, $V_{comp \ supply} = 5V$ unless otherwise stated.

NOTES:

(a) $V_{SENSE} = (V_{SENSE+}) - (V_{SENSE})$ (b) Level of V_{SENSE+} where comparator output defaults to 'off'.

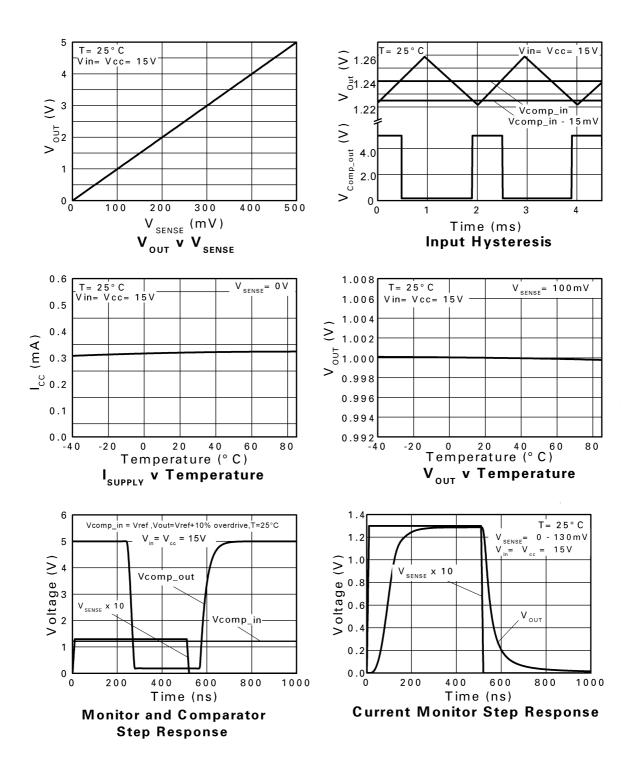
Symbol	Parameter	Conditions		Limits		Unit
			Min.	Typ. Max.		
V _{CC}	V _{CC} range		2.2		20	V
V _{SENSE+}	Sense+ range		2.2		V _{CC}	
V _{OUT}	Output voltage	V _{SENSE} = 0V	0	2	10	mV
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	Supply current	V _{SENSE-} = 15V	170	270	350	μA
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I _{SENSE-}	V _{SENSE-} input current	V _{SENSE-} = 14.9V		70	220	nA
V _{CM(min)} ^(b)	Minimum active common	$V_{CC} = 15V$	2.8			V
Civi(IIIII)	mode voltage	$V_{comp_{supply}} = 5V$				
		$V_{comp_in} = V_{REF}$				
		$V_{SENSE} = 10mV$				
A _{CC}	Accuracy	V _{SENSE} =100mV	-3		3	%
Gain	V _{OUT} /V _{SENSE}	V _{SENSE} = 100mV	9.7	10.0	10.3	
BW	Bandwidth	V _{SENSE} =10mVp-p		3		MHz
		V _{SENSE} = 100mVp-p		6		MHz
Comparat	or			l		
V _{comp_in}	Input voltage		0.005		10	V
V _H	Hysteresis			15		mV
IB	Input bias		5	80	150	nA
T _D	Propagation delay			100		ns
V _{OL}	Output voltage low		30	150	200	mV
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					supply	
I _{OL}	Output sink current	V _{OL} = 0.4V	2			mA
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PSR	Supply rejection			0.01		%/V

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NOTES:

(c) $V_{SENSE} = (V_{SENSE+}) - (V_{SENSE}-)$ (d) Level of V_{SENSE+} where comparator output defaults to 'off'.

Typical characteristics



Voltage output current monitor

Referring to the block diagram, the current monitor takes the small voltage developed across the sense resistor (V_{SENSE}) and transfers it from the large common mode supply voltage to a ground-referenced signal with a gain of 10. The sense input common mode range is 2.2V to 20V. In this range, a linear output voltage is delivered.

Reference

The bandgap reference allows the comparator to compare the translated Vsense with threshold value chosen by the user which can be any voltage from 0 to 1.24V, configured by two external resistors which forms V_{comp_in} .

The output current which can be drawn from the comparator reference (I_{ref} source) is limited to 5µA, making potentiometers $\ge 250 k\Omega$ suitable for setting a threshold level. Where a lower potentiometer resistor value is used, an additional resistor value should be inserted between V_{ref} and V_{CC} to maintain sufficient current for the reference. (as shown in Figure 1).

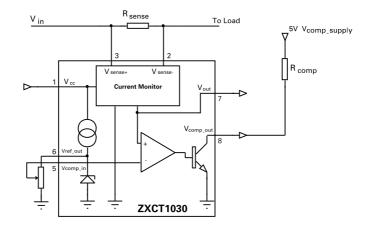


Figure 1: External resistor for reference level

The voltage reference has a maximum current sink capability. This magnitude of current will be influenced by the value of R1 which is inserted between V_{ref} and V_{CC} . The value of current flowing through R1 can be expressed as:

$$I = (V_{CC} - V_{ref}) / R1$$

Comparator

The open collector output is active low and is asserted when $V_{SENSE} \times 10 (V_{OUT}) > V_{comp_in}$.

It can be connected to any voltage rail up to Vin via a pull-up resistor. Suggest values for the resistor are in the range of 10-100k Ω .

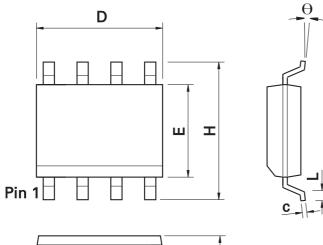
In the case where high load currents or a short circuit occurs, thus reducing the common mode signals (V+, V-) typically below 2.2V, the comparator will default to the asserted state. This can eliminate a closed loop system 'latch-up' condition, allowing the controller to remove the applied power.

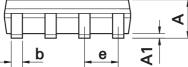
Stability

To ensure stable operation of the ZXCT1030, it is recommended a decoupling capacitor is placed across the V_{CC} and ground connections. A ceramic 10μ F will be adequate.

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Package outline - SO8



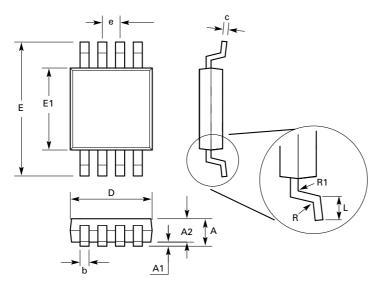


Seating Plane

DIM	Inc	hes	Millin	neters	DIM Inches M		Inches		illimeters	
	Min.	Max.	Min.	Max.		Min.	Max.	Min.	Max.	
Α	0.053	0.069	1.35	1.75	е	0.050	BSC	1.27	BSC	
A1	0.004	0.010	0.10	0.25	b	0.013	0.020	0.33	0.51	
D	0.189	0.197	4.80	5.00	С	0.008	0.010	0.19	0.25	
Н	0.228	0.244	5.80	6.20	θ	0°	8°	0°	8°	
E	0.150	0.157	3.80	4.00	h	0.010	0.020	0.25	0.50	
L	0.016	0.050	0.40	1.27	-	-	-	-	-	

Note: Controlling dimensions are in inches. Approximate dimensions are provided in millimeters

Package outline - MSOP8



DIM	Millin	neters	Inc	hes
	Min.	Max.	Min.	Max.
A	-	1.10	-	0.0433
A1	0.05	0.15	0.002	0.006
A2	0.75	0.95	0.0295	0.0374
b	0.25	0.40	0.010	0.0157
C	0.13	0.23	0.005	0.009
D	2.90	3.10	0.114	0.122
E	4.90	BSC	0.193 BSC	
E1	2.90	3.10	0.114	0.122
е	0.65	BSC	0.025	BSC
L	0.40	0.70	0.0157	0.0192
R	0.07	-	0.0027	-
R1	0.07	-	0.0027	-

Note: Controlling dimensions are in millimeters. Approximate dimensions are provided in inches

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